

Form PTO-1449						ATTY. DOCKET NO. 0020-5187P		APPLICATION NO. New		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)						APPLICANT YAGURA, Motoji				
						FILING DATE October 29, 2003		GROUP		
U.S. PATENT DOCUMENTS										
EXAMINER INITIAL	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE			
	US									
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FOREIGN PATENT DOCUMENTS										
	Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES NO		
MH	JP	6-37015	A	1994-02-10	JAPAN			Spe		
MH	JP	2000-323491	A	2000-11-24	JAPAN			Spe		
OTHER DOCUMENTS (Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.										
MH	Sugahara et al., IEEE, GaAs IC Symposium, pp. 115-118 (1993)									
MH	Kawano et al., SA-8-1, "Reliability of C-doped base InGaP/GaAs HBTs," pp. 474-475									
MH	Bahl et al., IEEE, International Electron Devices Meeting, pp. 815-818 (1995)									
EXAMINER	[Signature]				DATE CONSIDERED 08/11/04					
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